



44 FARRAND STREET  
BLOOMFIELD, NJ 07003  
(973) 748-5089

## NTE5629 TRIAC – 400V<sub>RM</sub>, 4Amp

### Description:

The NTE5629 TRIAC is a bi-directional triode thyristor in a TO202 type case. This device may be switched from off-state to conduction for either polarity of applied voltage with positive or negative gate-trigger current. The NTE5629 can be driven directly with IC and MOS devices and is designed for control applications in lighting, heating, cooling, and static switching relays.

### Absolute Maximum Ratings:

Repetitive Peak Off-State Voltage (Gate Open, $T_J = +110^\circ\text{C}$ , Note 1), $V_{\text{DRM}}$ .....	400V
RMS On-State Current ( $T_C = +80^\circ\text{C}$ , Conduction Angle = 360°), $I_T(\text{RMS})$ .....	4A
Non-Repetitive Peak Surge On-State Current (One-Cycle, at 50Hz or 60Hz), $I_{\text{TSM}}$ .....	40A
Peak Gate-Trigger Current (for 3μs Max), $I_{\text{GTM}}$ .....	1.2A
Peak Gate-Power Dissipation ( $I_{\text{GT}} \leq I_{\text{GTM}}$ ), $P_{\text{GM}}$ .....	15W
Average Gate-Power Dissipation, $P_{\text{G(AV)}}$ .....	3W
Operating Temperature Range, $T_{\text{opr}}$ .....	-40° to +110°C
Storage Temperature Range, $T_{\text{stg}}$ .....	-40° to +150°C
Thermal Resistance, Junction-to-Case, $R_{\text{thJC}}$ .....	4°C/W Typ

### Electrical Characteristics: (At Specified Case Temperature)

Peak Off-State Current (Gate Open, $T_C = +110^\circ\text{C}$ , $V_{\text{DRM}} = 400\text{V}$ , Note 1), $I_{\text{DRM}}$ .....	0.5mA Max
Maximum On-State Voltage ( $T_C = +25^\circ\text{C}$ , $I_T = 4\text{A}$ , Note 1), $V_{\text{TM}}$ .....	1.6V Max
DC Holding Current (Gate Open, $T_C = +25^\circ\text{C}$ , Note 1), $I_{\text{Hold}}$ .....	5mA Max
Critical Rate-of-Rise of Off-State Voltage, Critical dv/dt ( $V_D = 400\text{V}$ , Gate Open, $T_C = +110^\circ\text{C}$ , Note 1) .....	10V/μs
Critical rate-of-Rise of commutation Voltage, Commutating dv/dt ( $V_D = 400\text{V}$ , $I_T = 4\text{A}$ , Gate Unenergized, $T_C = +80^\circ\text{C}$ , Note 1) .....	1V/μs
DC Gate-Trigger Current ( $V_D = 12\text{VDC}$ , $R_L = 60\Omega$ , $T_C = +25^\circ\text{C}$ ), $I_{\text{GT}}$ .....	3mA Max
( $T_2+$ Gate +, $T_2-$ Gate -) Quads I and III	
( $T_2+$ Gate -, $T_2-$ Gate +) Quads II and IV	
DC Gate-Trigger Voltage ( $V_D = 12\text{VDC}$ , $R_L = 60\Omega$ , $T_C = +25^\circ\text{C}$ ), $V_{\text{GT}}$ .....	2V Max
Gate-Controlled Turn-On Time, $T_{\text{gt}}$ ( $V_D = 400\text{V}$ , $I_{\text{GT}} = 80\text{mA}$ , $t_R = 0.1\mu\text{s}$ , $I_T = 6\text{A}$ (Peak), $T_C = +25^\circ\text{C}$ ) .....	3μs

Note 1. All values apply in either direction.

